## HiPerFRED ${ }^{\text {TM }}$ Epitaxial Diode with common cathode and soft recovery

| $V_{\text {RSM }}$ <br> $V$ | $V_{\text {RRM }}$ <br> $V$ | Type |
| :---: | :---: | :--- |
| 400 | 400 | DSEC $30-04 \mathrm{~A}$ |



| Symbol | Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {frMs }}$ |  | 50 | A |
| $\mathrm{I}_{\text {FAVM }}$ | $\mathrm{T}_{\mathrm{C}}=145^{\circ} \mathrm{C}$; rectangular, $\mathrm{d}=0.5$ | 15 | A |
| $I_{\text {fSM }}$ | $\mathrm{T}_{\mathrm{v},}=45^{\circ} \mathrm{C} ; \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}(50 \mathrm{~Hz})$, sine | tbd | A |
| $\mathrm{E}_{\text {AS }}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{vJ}}=25^{\circ} \mathrm{C} ; \text { non-repetitive } \\ & \mathrm{I}_{\mathrm{AS}}=\operatorname{tbd} \mathrm{A} ; \mathrm{L}=\operatorname{tbd} \mu \mathrm{H} \end{aligned}$ | tbd | mJ |
| $\mathrm{I}_{\text {AR }}$ | $\mathrm{V}_{A}=1.5 \cdot \mathrm{~V}_{\mathrm{R}}$ typ.; $\mathrm{f}=10 \mathrm{kHz}$; repetitive | tbd | A |
| $\mathrm{T}_{\mathrm{v}}$ |  | -55...+175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {vJM }}$ |  | 175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | -55...+150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\text {tot }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 95 | W |
| $\mathrm{M}_{\mathrm{d}}$ | mounting torque | 0.8...1.2 | Nm |
| Weight | typical | 6 | g |


| Symbol | Conditions | Characteristic Values typ. max. |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{R}} \quad 1$ | $\begin{array}{ll} \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C} ; & \mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\mathrm{RRM}} \\ \mathrm{~T}_{\mathrm{VJ}}=150^{\circ} \mathrm{C} ; & \mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\text {RRM }} \end{array}$ |  | $\begin{array}{r} 100 \\ 0.5 \end{array}$ | $\mu \mathrm{A}$ mA |
| $\mathrm{V}_{\mathrm{F}}{ }^{(2)}$ | $\begin{array}{ll} \mathrm{I}_{\mathrm{F}}=15 \mathrm{~A} ; & \mathrm{T}_{\mathrm{V} J}=150^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{V},}=25^{\circ} \mathrm{C} \end{array}$ |  | $\begin{aligned} & 1.06 \\ & 1.47 \end{aligned}$ | V |
| $\begin{aligned} & \overline{\mathbf{R}_{\mathrm{thJc}}} \\ & \mathbf{R}_{\mathrm{thch}} \end{aligned}$ |  | 0.25 | 1.6 | KW KW |
| $\mathrm{trr}_{\text {r }}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=1 \mathrm{~A} ;-\mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mathrm{Ls} ; \\ & \mathrm{V}_{\mathrm{R}}=30 \mathrm{~V} ; \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C} \end{aligned}$ | 30 |  | ns |
| $\mathrm{I}_{\text {RM }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=100 \mathrm{~V} ; \mathrm{I}_{\mathrm{F}}=25 \mathrm{~A} ;-\mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mu \mathrm{s} \\ & \mathrm{~T}_{\mathrm{VJ}}=100^{\circ} \mathrm{C} \end{aligned}$ | 5.0 | 6.3 | A |

## Pulse test: (1) Pulse Width = 5 ms , Duty Cycle $<2.0$ \%

(2) Pulse Width $=300 \mu \mathrm{~s}$, Duty Cycle $<2.0 \%$

Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, test conditions and dimensions.

TO-247 AD


A = Anode,$C=$ Cathode,$T A B=$ Cathode
$\mathrm{t}_{\text {fav }}=2 \times 15 \mathrm{~A}$
$\mathrm{~V}_{\text {RRM }}=400 \mathrm{~V}$
$\mathrm{t}_{\mathrm{rr}}=30 \mathrm{~ns}$

A = Anode $\mathrm{C}=$ Catho $\mathrm{TAB}=$ Cathode

## Features

- International standard package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low $\mathrm{I}_{\mathrm{Rm}}$-values
- Soft recovery behaviour
- Epoxy meets UL 94V-0


## Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders


## Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low $\mathrm{I}_{\mathrm{Rm}}$ reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch


## Dimensions see pages IXYS Data Book

